

FJX3904

General Purpose Transistor



SOT-323

1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	60	V
V _{CES}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	350	mW
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	neter Test Condition		Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μA, I _E =0	60 40	- 17	V
BV _{CEO}	* Collector-Emitter Breakdown Voltage	I _C =1mA, I _B =0		. 0.75	
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	6	M	V
I _{CEX}	Collector Cut-off Current	V _{CE} =30V, V _{EB} =3V		50	nA
h _{FE}	* DC Current Gain	V _{CE} =1V, I _C =0.1mA V _{CE} =1V, I _C =1mA V _{CE} =1V, I _C =10mA V _{CE} =1V, I _C =50mA V _{CE} =1V, I _C =100mA	40 70 100 60 30	300	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I_C =10mA, I_B =1mA I_C =50mA, I_B =5mA		0.2 0.3	V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =10mA, I _B =1mA I _C =50mA, I _B =5mA	0.65	0.85 0.95	V
C _{ob}	Output Capacitance	Capacitance V _{CB} =5V, I _E =0, f=1MHz		4	pF
f _T	Current Gain Bandwidth Product	V _{CE} =20V, I _C =10mA	300	L NZ	MHz
NF	Noise Figure	I_C =100μA, V_{CE} =5V, R_S =1KΩ f=10Hz to 15.7KHz	W.A.	5	dB
t _{ON}	Turn On Time	V _{CC} =3V, V _{BE} =0.5V I _C =10mA, I _{B1} =1mA		70	ns
t _{OFF}	Turn Off Time	V _{CC} =3V, I _C =10mA I _{B1} =I _{B2} =1mA		250	ns

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%





Typical Characteristics

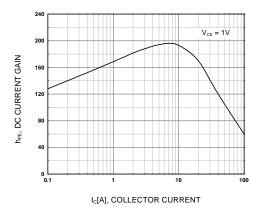


Figure 1. DC current Gain

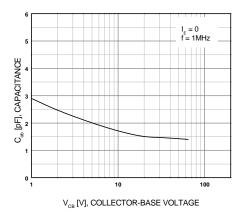


Figure 3. Output Capacitance

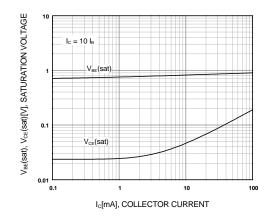


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

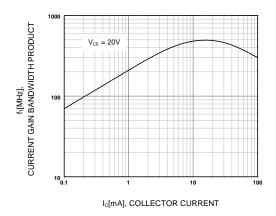
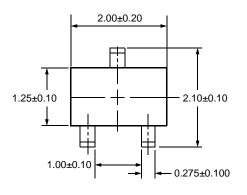


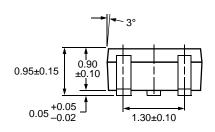
Figure 4. Current Gain Bandwidth Product

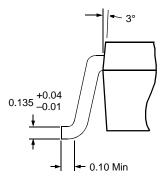
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Package Dimensions

SOT-323







Dimensions in Millimeters

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